#### [CLAIMS]

#### [Claim 1]

A magnesium titanate implant, comprising:

an implant body containing titanium or a titanium alloy; and a magnesium titanate oxide film formed on the surface of the body.

#### [Claim 2]

The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film is prepared in a single or mixed solution containing magnesium by low voltage dielectric breakdown anodic oxidation.

### 10 [Claim 3]

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The magnesium titanate implant as set forth in claim 1 or 2, wherein the magnesium titanate oxide film contains 6 to 26% of titanium, 51 to 71% of oxygen and 1.8 to 32% of magnesium, as main ingredients.

#### [Claim 4]

The magnesium titanate implant as set forth in claim 1 or 2, wherein the magnesium titanate oxide film has a bilayer structure including an upper porous layer and a lower barrier layer.

#### [Claim 5]

The magnesium titanate implant as set forth in claim 1 or 2, wherein the magnesium titanate oxide film has a thickness of 300 nm to 30  $\mu$ m.

#### [Claim 6]

The magnesium titanate implant as set forth in claim 5, wherein the magnesium titanate oxide film has a thickness of 500 nm to  $10 \mu m$ .

#### [Claim 7]

A process for preparing a magnesium titanate oxide film implant, comprising:

irradiating UV light on an implant body made of titanium or a titanium alloy in distilled water for more than 2 hours;

dipping the UV light-irradiated implant body in an electrolyte solution containing magnesium; and

30 coating a magnesium titanate oxide film on the dipped implant body by anodic oxidation at a voltage of 60 to 500V.

# [Claim 8]

The process as set forth in claim 7, wherein the electrolyte solution is a single or mixed solution containing magnesium.

# [Claim 9]

The process as set forth in claim 7 or 8, wherein the electrolyte solution has a concentration ranging from 0.01M to 1.0M.

# [Claim 10]

The process as set forth in claim 7 or 8, wherein the electrolyte solution has a pH of 3.0 to 12.5.

# 10 [Claim 11]

The process as set forth in claim 7 or 8, wherein the current density for performing the anodic oxidation is within the range of 30 to 4000 mA/cm<sup>2</sup>.

#### AMENDED CLAIMS

[received by the International Bureau on 30 June 2005 (30.06.2005); original claims 1 and 3-5 amended; original claim 2 cancelled; remaining claims unchanged (2 pages)]

#### [CLAIMS]

#### [Claim 1]

A magnesium titanate implant, comprising:

an implant body containing titanium or a titanium alloy; and

a magnesium titanate oxide film formed on the surface of the said implant body in a single or mixed solution containing magnesium by low voltage dielectric breakdown anodic oxidation.

#### [Claim 3]

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The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film contains 6 to 26% of titanium, 51 to 71% of oxygen and 1.8 to 32% of magnesium, as main ingredients.

#### [Claim 4]

The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film has a bilayer structure including an upper porous layer and a lower barrier layer.

#### (Claim 5)

The magnesium titanate implant as set forth in claim 1, wherein the magnesium titanate oxide film has a thickness of 300 nm to 30  $\mu$ m.

#### [Claim 6]

The magnesium titanate implant as set forth in claim 5, wherein the magnesium titanate oxide film has a thickness of 500 nm to  $10 \mu m$ .

#### [Claim 7]

A process for preparing a magnesium titanate oxide film implant, comprising:

irradiating UV light on an implant body made of titanium or a titanium alloy in distilled water for more than 2 hours;

dipping the UV light-irradiated implant body in an electrolyte solution containing magnesium; and

coating a magnesium titanate oxide film on the dipped implant body by anodic oxidation at a voltage of 60 to 500V.

#### 30 [Claim 8]

The process as set forth in claim 7, wherein the electrolyte solution is a single or mixed solution containing magnesium.

# (Claim 9)

The process as set forth in claim 7 or 8, wherein the electrolyte solution has a concentration ranging from 0.01M to 1.0M.

# [Claim 10]

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The process as set forth in claim 7 or 8, wherein the electrolyte solution has a pH of 3.0 to 12.5.

# [Claim 11]

The process as set forth in claim 7 or 8, wherein the current density for performing the anodic oxidation is within the range of 30 to 4000 mA/cm<sup>2</sup>.